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All-optical logic gates and a half-adder based on lithium niobate photonic crystal micro-cavities

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All-optical logic gates including AND, XOR, and NOT gates, as well as a half-adder, are realized based on two-dimensional lithium niobate photonic crystal (PhC) circuits with PhC micro-cavities. The proposed all-optical devices have an extinction ratio as high as 23 dB due to the effective all-optical switch function induced by two-missing-hole micro-cavities. These proposed devices can have potential implementation of complex integrated optical functionalities including all-optical computing in a lithium niobate slab or thin film.

Current all-optical logic gates are predominantly fabricated in optical fiber waveguides, which make it difficult to integrate on small integrated chips1–4, whereas defect waveguides in photonic crystals (PhCs) possess small scale and unique light controlling ability5 that make it a crucial method to design miniaturized all-optical logic gates. Until now, all-optical logic gates are mostly designed and integrated on silicon-based PhC materials5,6. However, the two-photon absorption and third-order nonlinearity in silicon may cause nonlinear loss and signal crosstalk, which results in low extinction ratio in silicon logic gates. Consequently, a new optical material integration platform is demanded, such as lithium niobate (LiNbO3, LN), which attracts more research interests where second-order nonlinearity is dominated. LN also possesses unique electro-optic, acousto-optic, piezoelectric, and other physical properties6–8. So, LN and LN thin film (LNOI)9–11 could be the ideal materials for the development of the integrated optical circuits. Based on the above photonics platform, developing all-optical logic gates is significant in integrated photonics computing.

We have experimentally demonstrated polarization-based binary optical logic gates by employing the Pockels effect in periodically poled LN in our previous research works12–14, where we only get an extinction ratio of about 10 dB. In this Letter, we have designed three basic all-optical logic gates with 23 dB, including AND, XOR, and NOT gates in an LN PhC by employing PhC micro-cavities. We have found that the extinction ratio between the logic 1 and 0 states can be improved by adding PhC-defect micro-cavities in the PhC circuits15–18. By utilizing the single-line-defect (W1) waveguides and two-missing-hole (L2) cavities, the extinction ratio of the logic gates designed can reach a maximum as high as 23 dB in the finite-difference time-domain (FDTD) simulations (the simulated software used is RSOFT). It is the highest extinction ratio obtained, to the best of our knowledge, compared with 20.53 dB in silicon PhC19. Finally, an all-optical half-adder was also designed and realized effectively by the combination of these basic logic gates in an LN PhC.

Figure 1(a) shows the band diagrams and square lattice sketch of a two-dimensional square lattice PhC with 5% MgO-doped LN rods, where $r$ is the radius of the rods, and $a$ is the lattice constant, respectively. The duty ratio is set as $r/a = 0.26$, and the refractive index of 5% MgO-doped LN rods was calculated by employing the Sellmeier equation at the 1.55 μm wavelength20. The band diagrams of this lattice structure are simulated by the plane wave expansion method (PWE). It shows that this lattice structure has large transverse electric (TE) mode band gap ranging from 0.38 ($a/\lambda$) to 0.43 ($a/\lambda$). Under the condition of the 1.55 μm C-band window with a corresponding 0.40 ($a/\lambda$) band gap, the lattice constant of the PhC can be calculated as 0.620 μm.

The light cannot propagate in the PhC forbidden band. However, the defect waveguides called W1 waveguides21 in the PhC possess unique light guiding ability due to the

![Fig. 1. (a) Band diagrams in a square lattice PhC with LN (MgO-doped) rods for TE and TM modes. (b) The left is the schematic structure of the W1 waveguide in the Γ-M direction; the right is the FDTD simulation result of the W1 waveguide and the sketch of the light beam coherent interference.](image-url)
The existence of the band gap. So the W1 waveguide is designed as the basic element of the all-optical logic gates in LN PhC structures. The PhC line-defect waveguide is fabricated by removing the line rods, as shown in the left of Fig. 1(b). According to the wave optics theory, if the phase difference between the two light beams that are incident from input A and input B is $2k\pi$ (where $k = 0, 1, 2, ...$), then constructive interference can occur, and the output light will have high power (corresponding to logic state 1 as the output C performance). On the contrary, destructive interference can occur when the phase difference is $(2k + 1)\pi$ (where $k = 0, 1, 2, ...$), and the output light will be approximately zero (corresponding to logic state 0 as the output D performance).

The W1 waveguide can guide the light in the PhC structure, and besides, the point-defect micro-cavities located next to the line-defect waveguides in PhC can effectively affect the transmission of the light beams. There are several different micro-cavities in the PhC, one of which is the other basic element called the L2 cavity formed by getting rid of two adjacent rods. Figure 2 demonstrates the all-optical switch function of the L2 cavity. The T-shape W1 waveguide without the L2 cavity in Fig. 2(a) has the same relative output intensity, which approximately equals 0.3 in the two opposite output ports, A and B. When the L2 cavity is located near the output B port, the relative output intensity in output B is reduced to 0.2. Due to the light coupling effect of the L2 cavity, the relative output intensity in output A can be enhanced to 0.4, as shown in Fig. 2(b). The modulation results demonstrate that the L2 cavity can assist the W1 waveguide to realize the desired splitting ratio of the light beams.

Here, we proposed a complicated LN PhC structure to realize three basic all-optical logic gates and a half-adder with a high extinction ratio by combining the W1 waveguides with L2 cavities. Figure 3 shows the schematic structures of the three fundamental all-optical logic gates. First, the AND gate is composed of two L2 cavities located next to the input A and input B ports, as shown in Fig. 3(a), and the output C port is placed at the position where constructive interference can occur. When the two L2 cavities are located near the output C port, this structure can form the XOR gate, as illustrated by Fig. 3(b). The NOT gate is realized by replacing the input B port by the control port whose logic state is always set as 1 on the basis of XOR gate, as shown in Fig. 3(c).

Figure 4 shows the FDTD simulated transmission of the AND and XOR gates in an LN PhC. The input logic state 1 corresponds to the input light value over 0.5, as the black dotted line. Output logic state 1 corresponds to the value higher than 0.6 when input $A = 1$ and $B = 1$, while output

Table 1. Truth Table for the AND, XOR, and NOT Logic Gates

<table>
<thead>
<tr>
<th>Input A</th>
<th>Input B</th>
<th>AND</th>
<th>XOR</th>
<th>NOT</th>
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<tr>
<td>0</td>
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</table>

Fig. 2. T-shape W1 waveguides (a) without or (b) with the L2 cavity in an LN PhC and the FDTD simulated different transmission results.

Fig. 4. FDTD simulated transmission of (a) AND and (b) XOR gates in an LN PhC.
logic gates and an all-optical half-adder in an LN PhC, which has the highest extinction ratio of 23 dB compared with that in silicon logic gates\textsuperscript{15}. This logic gate design may benefit complex integrated all-optical functionalities in the LN or LNOI photonics device platform, such as optical quantum computing by combining parametric down-conversion nonlinear processes\textsuperscript{22}.

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References

Table 2. Truth Table for the All-optical Half-adder

<table>
<thead>
<tr>
<th>Input A</th>
<th>Input B</th>
<th>Output C (Carry Digit)</th>
<th>Output S (Sum Digit)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
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</table>

Fig. 5. (a) Schematic structure of the all-optical half-adder in an LN PhC. (b) The FDTD simulated transmission of the all-optical half-adder.